Class-D audio amplifier

Rev. 01 — 11 May 2006

Preliminary data sheet

1. General description

The TDA8932 is a high efficiency class-D amplifier with low power dissipation.

The maximum output power is 2×25 W in stereo half-bridge application ($R_L=4~\Omega$) or 1×50 W in mono full-bridge application ($R_L=8~\Omega$). Due to the low power dissipation the device can be used without any external heat sink when playing music. If proper cooling via the printed-circuit board is implemented, a continuous output power of 2×15 W is feasible. Due to the implementation of thermal foldback, even for high supply voltages and/or lower load impedances, the device remains operating with considerable music output power without the need for an external heat sink.

The device has two full-differential inputs driving two independent outputs. It can be used as mono full-bridge configuration (BTL) or as stereo half-bridge configuration (SE).

2. Features

- Operating voltage from 10 V to 36 V asymmetrical or ±5 V to ±18 V symmetrical
- Mono-bridged tied load (full-bridge) or stereo single-ended (half-bridge) application
- Application without heatsink using thermally enhanced small outline package
- High efficiency and low-power dissipation
- Thermally protected and thermal foldback
- Current limiting to avoid audio holes
- Full short-circuit proof across load and to supply lines (using advanced current protection)
- Switchable internal or external oscillator (master-slave setting)
- No pop noise
- Full differential inputs

3. Applications

- Flat panel television sets
- Flat panel monitor sets
- Multimedia systems
- Wireless speakers
- Mini and micro systems
- Home sound sets



Class-D audio amplifier

4. Quick reference data

Table 1. Quick reference data

| Table 1. | Quick reference data | | | | | | | | |
|---------------------|-----------------------------|---|-----|-----|-----|------|--|--|--|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | | | |
| General: | $V_P = 22 V, f_{osc} = 320$ | kHz; T _{amb} = 25 °C | | | | | | | |
| V_{P} | supply voltage | asymmetrical supply | 10 | 22 | 36 | V | | | |
| I_P | supply current | Sleep mode; no load | - | 0.6 | 1 | mA | | | |
| I _{q(tot)} | total quiescent current | Operating mode; no load, snubbers and filter connected | - | 40 | 80 | mA | | | |
| Stereo S | Stereo SE channel[1] | | | | | | | | |
| P _{o(RMS)} | RMS output power | continuous time output power per channel; THD+N = 10 %; f_i = 1 kHz | | | | | | | |
| | | $R_L = 4 \Omega$; $V_P = 22 V$ | 14 | 15 | - | W | | | |
| | | $R_L = 8 \Omega$; $V_P = 30 V$ | 14 | 15 | - | W | | | |
| | | short time output power per channel; THD+N = 10 % | | | | | | | |
| | | $R_L = 4 \Omega; V_P = 29 V$ | 23 | 25 | - | W | | | |
| Mono B1 | rL <u>[1]</u> | | | | | | | | |
| P _{o(RMS)} | RMS output power | continuous time output power; THD+N = 10 %; f_i = 1 kHz | | | | | | | |
| | | $R_L = 4 \Omega$; $V_P = 12 V$ | 14 | 15 | - | W | | | |
| | | $R_L = 8 \Omega$; $V_P = 22 V$ | 28 | 30 | - | W | | | |
| | | short time output power; THD+N = 10 % | | | | | | | |
| | | $R_L = 8 \Omega; V_P = 29 V$ | 47 | 50 | - | W | | | |
| | | | | | | | | | |

^[1] Output power is measured indirectly; based on R_{DSon} measurement.

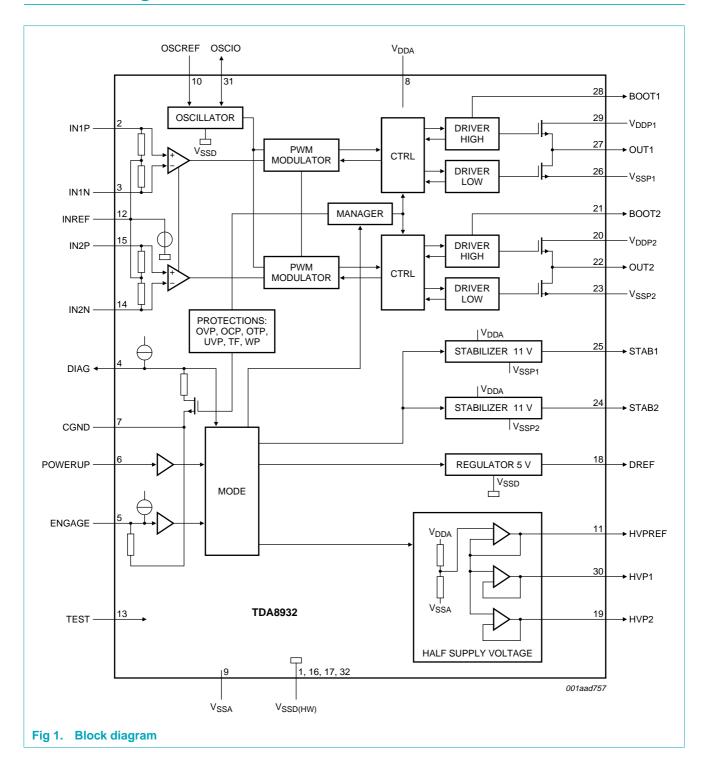
5. Ordering information

Table 2. Ordering information

| Type number | Package | | | | | |
|-------------|----------|--|----------|--|--|--|
| | Name | Description | Version | | | |
| TDA8932T | SO32 | plastic small outline package; 32 leads; body width 7.5 mm | SOT287-1 | | | |
| TDA8932TW | HTSSOP32 | plastic thermal enhanced thin shrink small outline package; 32 leads; body width 6.1 mm; lead pitch 0.65 mm; exposed die pad | SOT549-1 | | | |

Class-D audio amplifier

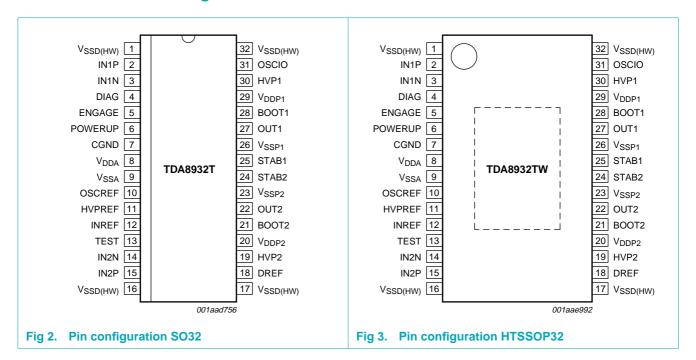
6. Block diagram



Class-D audio amplifier

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|----------------------|-----|---|
| $V_{\text{SSD(HW)}}$ | 1 | negative digital supply voltage and handle wafer connection |
| IN1P | 2 | positive audio input for channel 1 |
| IN1N | 3 | negative audio input for channel 1 |
| DIAG | 4 | diagnostic output; open-drain |
| ENGAGE | 5 | engage input to switch between Mute mode and Operating mode |
| POWERUP | 6 | power-up input to switch between Sleep mode and Mute mode |
| CGND | 7 | control ground; reference for POWERUP, ENGAGE and DIAG |
| V_{DDA} | 8 | positive analog supply voltage |
| V_{SSA} | 9 | negative analog supply voltage |
| OSCREF | 10 | input internal oscillator setting (only master setting) |
| HVPREF | 11 | decoupling of internal half supply voltage reference |
| INREF | 12 | decoupling for input reference voltage |
| TEST | 13 | test signal input; for testing purpose only |
| IN2N | 14 | negative audio input for channel 2 |
| IN2P | 15 | positive audio input for channel 2 |
| V _{SSD(HW)} | 16 | negative digital supply voltage and handle wafer connection |
| V _{SSD(HW)} | 17 | negative digital supply voltage and handle wafer connection |
| DREF | 18 | decoupling of internal (reference) 5 V regulator for logic supply |

Class-D audio amplifier

 Table 3.
 Pin description ...continued

| | 4000. | |
|----------------------|-------|--|
| Symbol | Pin | Description |
| HVP2 | 19 | half supply output voltage 2 for charging single-ended capacitor for channel 2 |
| V_{DDP2} | 20 | positive power supply voltage for channel 2 |
| BOOT2 | 21 | bootstrap high-side driver channel 2 |
| OUT2 | 22 | PWM output channel 2 |
| V_{SSP2} | 23 | negative power supply voltage for channel 2 |
| STAB2 | 24 | decoupling of internal 11 V regulator for channel 2 drivers |
| STAB1 | 25 | decoupling of internal 11 V regulator for channel 1 drivers |
| V_{SSP1} | 26 | negative power supply voltage for channel 1 |
| OUT1 | 27 | PWM output channel 1 |
| BOOT1 | 28 | bootstrap high-side driver channel 1 |
| V_{DDP1} | 29 | positive power supply voltage for channel 1 |
| HVP1 | 30 | half supply output voltage 1 for charging single-ended capacitor for channel 1 |
| OSCIO | 31 | oscillator input in slave configuration or oscillator output in master configuration |
| $V_{\text{SSD(HW)}}$ | 32 | negative digital supply voltage and handle wafer connection |
| Exposed dipad | e - | HTSSOP32 package only ^[1] |
| | | |

^[1] The exposed die pad has to be connected to $V_{\mbox{\footnotesize SSD(HW)}}.$

Class-D audio amplifier

8. Functional description

8.1 General

The TDA8932 is a mono full-bridge or stereo half-bridge audio power amplifier using class-D technology. The audio input signal is converted into a Pulse Width Modulated (PWM) signal via an analog input stage and PWM modulator. To enable the output power Diffusion Metal Oxide Semiconductor (DMOS) transistors to be driven, this digital PWM signal is applied to a control and handshake block and driver circuits for both the high side and low side. A 2nd-order low-pass filter converts the PWM signal to an analog audio signal across the loudspeakers.

The TDA8932 contains two independent half-bridges with full differential input stages. The loudspeakers can be connected in the following configurations:

- Mono full-bridge: Bridge Tied Load (BTL)
- Stereo half-bridge: Single-Ended (SE)

The TDA8932 contains common circuits to both channels such as the oscillator, all reference sources, the mode functionality and a digital timing manager. The following protections are built-in: thermal foldback, temperature, current and voltage protections.

8.2 Mode selection and interfacing

The TDA8932 can be switched in three operating modes using pins POWERUP and ENGAGE:

- Sleep mode: with low supply current.
- Mute mode: the amplifiers are switching idle (50 % duty cycle), but the audio signal at the output is suppressed by disabling the VI-converter input stages. The capacitors on pins HVP1 and HVP2 have been charged to half the supply voltage (asymmetrical supply only).
- Operating mode: the amplifiers are fully operational with output signal.
- · Fault mode.

Both pins POWERUP and ENGAGE refer to pin CGND.

<u>Table 4</u> shows the different modes as function of the voltages on the POWERUP and ENGAGE pins.

Table 4. Mode selection

| Mode | Pin | | | | | |
|-----------|-----------------|-----------------|------------|--|--|--|
| | POWERUP | ENGAGE | DIAG | | | |
| Sleep | < 0.8 V | < 0.8 V | don't care | | | |
| Mute | 2 V to 6.0 V[1] | < 0.8 V[1] | > 2 V | | | |
| Operating | 2 V to 6.0 V[1] | 3 V to 6.0 V[1] | > 2 V | | | |
| Fault | 2 V to 6.0 V[1] | don't care | < 0.8 V | | | |

^[1] In case of symmetrical supply conditions the voltage applied to pins POWERUP and ENGAGE must never exceed the supply voltage (V_{DDA}, V_{DDP1} or V_{DDP2}).

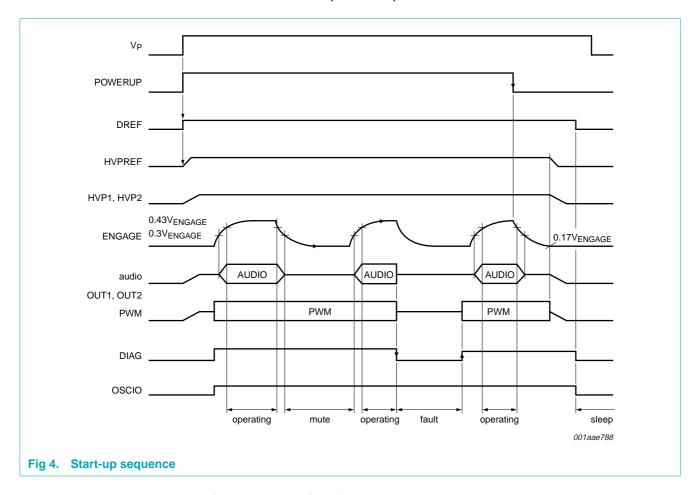
TDA8932_

Class-D audio amplifier

If the transition between Mute mode and Operating mode is controlled via a time constant, the start-up will be pop free since the DC output offset voltage is applied gradually to the output between Mute mode and Operating mode. The bias current setting of the VI-converters is related to the voltage on pin ENGAGE:

- Mute mode: the bias current setting of the VI-converters is zero (VI-converters disabled)
- Operating mode: the bias current is at maximum

The time constant required to apply the DC output offset voltage gradually between Mute mode and Operating mode can be generated by applying a decoupling capacitor on pin ENGAGE. The value of the capacitor on pin ENGAGE should be 470 nF.



8.3 Pulse width modulation frequency

The output signal of the amplifier is a PWM signal with a carrier frequency of approximately 320 kHz. Using a 2nd-order low-pass filter in the application results in an analog audio signal across the loudspeaker. The PWM switching frequency can be set by an external resistor $R_{\rm osc}$ connected between pins OSCREF and $V_{\rm SSD(HW)}.$ The carrier frequency can be set between 300 kHz and 500 kHz. Using an external resistor of 39 k Ω , the carrier frequency is set to an optimized value of 320 kHz (see Figure 5).

Class-D audio amplifier

If two or more TDA8932 devices are used in the same audio application, it is recommended to synchronize the switching frequency of all devices. This can be realized by connecting all pins OSCIO together and configure one of the TDA8932 in the application as clock master, while the other TDA8932 devices are configured in slave mode.

Pin OSCIO is a 3-state input or output buffer. Pin OSCIO is configured in master mode as oscillator output and in slave mode as oscillator input. Master mode is enabled by applying a resistor while slave mode is entered by directly connecting pin OSCREF to pin V_{SSD(HW)} (so without any resistor).

The value of the resistor also sets the frequency of the carrier and can be estimated by following formula:

$$f_{osc} = \frac{12.45 \times 10^9}{R_{osc}} \tag{1}$$

Where:

fosc = oscillator frequency

R_{osc} = oscillator resistor (on pin OSCREF)

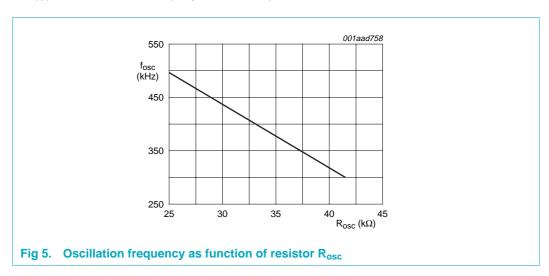


Table 5 summarizes how to configure the TDA8932 in master or slave configuration.

For device synchronization see Section 14.6 "Device synchronization".

Table 5. Master or slave configuration

| Configuration | Pin | | | | |
|---------------|--|--------|--|--|--|
| | OSCREF | OSCIO | | | |
| Master | $R_{\rm osc}$ > 25 k Ω to $V_{\rm SSD(HW)}$ | output | | | |
| Slave | $R_{osc} = 0 \Omega$; shorted to $V_{SSD(HW)}$ | input | | | |

Class-D audio amplifier

8.4 Protections

The following protections are included in the TDA8932:

- Thermal Foldback (TF)
- OverTemperature Protection (OTP)
- OverCurrent Protection (OCP)
- Window Protection (WP)
- Supply voltage protections:
 - UnderVoltage Protection (UVP)
 - OverVoltage Protection (OVP)
 - UnBalance Protection (UBP)
- ESD

The reaction of the device on the different fault conditions differs per protection.

8.4.1 Thermal Foldback (TF)

If the junction temperature of the TDA8932 exceeds the threshold level ($T_j > 140~^{\circ}C$) the gain of the amplifier is decreased gradually to a level were the combination of dissipation (P) and the thermal resistance from junction to ambient [$R_{th(j-a)}$] results into a junction temperature around the threshold level.

This means that the device will not completely switch off, but remains operational at lower output power levels. Especially with music output signals this feature enables high peak output powers while still operating without any external heat sink other than the printed-circuit board area.

If the junction temperature still increases due to external causes the OTP shuts down the amplifier completely.

8.4.2 OverTemperature Protection (OTP)

If the junction temperature $T_i > 155$ °C, then the power stage will shutdown immediately.

8.4.3 OverCurrent Protection (OCP)

When the loudspeaker terminals are short-circuited or if one of the demodulated outputs of the amplifier is short-circuited to one of the supply lines, this will be detected by the OCP.

If the output current exceeds the maximum output current ($I_{O(ocp)} > 4$ A), this current will be limited by the amplifier to 4 A while the amplifier outputs remain switching (the amplifier is NOT shutdown completely). This is called current limiting.

The amplifier can distinguish between an impedance drop of the loudspeaker and a low-ohmic short-circuit across the load or to one of the supply lines. This impedance threshold depends on the supply voltage used:

In case of a short-circuit across the load, the audio amplifier is switched off completely
and after approximately 100 ms it will try to restart again. If the short-circuit condition
is still present after this time, this cycle will be repeated. The average dissipation will
be low because of this low duty cycle.

Class-D audio amplifier

- In case of a short to one of the supply lines, this will trigger the OCP and the amplifier will be shutdown. During restart the window protection will be activated. As a result the amplifier will not start after 100 ms until the short to the supply lines is removed.
- In case of impedance drop (e.g. due to dynamic behavior of the loudspeaker) the same protection will be activated. The maximum output current is again limited to 4 A, but the amplifier will NOT switch off completely (thus preventing audio holes from occurring). The result will be a clipping output signal without any artifacts.

8.4.4 Window Protection (WP)

The WP checks the PWM output voltage before switching from Sleep mode to Mute mode (outputs switching) and is activated:

- During the start-up sequence, when pin POWERUP is switched from Sleep mode to
 Mute mode. In the event of a short-circuit at one of the output terminals to V_{DDP1},
 V_{SSP1}, V_{DDP2} or V_{SSP2} the start-up procedure is interrupted and the TDA8932 waits for
 open-circuit outputs. Because the check is done before enabling the power stages, no
 large currents will flow in the event of a short-circuit.
- When the amplifier is completely shutdown due to activation of the OCP because a short-circuit to one of the supply lines is made, then during restart (after 100 ms) the window protection will be activated. As a result the amplifier will not start until the short-circuit to the supply lines is removed.

8.4.5 Supply voltage protections

If the supply voltage drops below 10 V, the UnderVoltage Protection (UVP) circuit is activated and the system will shut down directly. This switch-off will be silent and without pop noise. When the supply voltage rises above the threshold level, the system is restarted again after 100 ms.

If the supply voltage exceeds 36 V the OverVoltage Protection (OVP) circuit is activated and the power stages will shut down. It is re-enabled as soon as the supply voltage drops below the threshold level. The system is restarted again after 100 ms.

It should be noted that supply voltages > 40 V may damage the TDA8932. Two conditions should be distinguished:

- 1. If the supply voltage is pumped to higher values by the TDA8932 application itself (see also <u>Section 14.3</u>), the OVP is triggered and the TDA8932 is shut down. The supply voltage will decrease and the TDA8932 is protected against any overstress.
- 2. If a supply voltage > 40 V is caused by other or external causes, then the TDA8932 will shut down, but the device can still be damaged since the supply voltage will remain > 40 V in this case. The OVP protection is not a supply voltage clamp.

An additional UnBalance Protection (UBP) circuit compares the positive analog supply voltage (V_{DDA}) and the negative analog supply voltage (V_{SSA}) and is triggered if the voltage difference between them exceeds a certain level. This level depends on the sum of both supply voltages. The unbalance threshold levels can be defined as follows:

- LOW-level threshold: V_{P(th)(ubp)I} < ⁸/₅ × V_{HVPREF}
- HIGH-level threshold: V_{P(th)(ubp)h} > ⁸/₃ × V_{HVPREF}

Class-D audio amplifier

In a symmetrical supply the UBP is released when the unbalance of the supply voltage is within 6 % of it starting value.

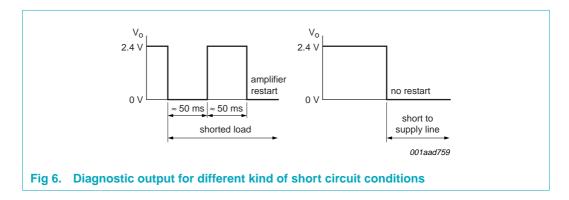
Table 6 shows an overview of all protections and the effect on the output signal.

Table 6. Overview protections

| Protection | Restart | | | | |
|------------|-----------------------|--------------|--|--|--|
| | When fault is removed | Every 100 ms | | | |
| OTP | no | yes | | | |
| OCP | yes | no | | | |
| WP | yes | no | | | |
| UVP | no | yes | | | |
| OVP | no | yes | | | |
| UBP | no | yes | | | |

8.5 Diagnostic input and output

Whenever one of the protections is triggered, except for TF, pin DIAG is activated to LOW level (see <u>Table 6</u>). An internal reference supply will pull-up the open-drain DIAG output to approximately 2.4 V. This internal reference supply can deliver approximately 50 μA . Pin DIAG refers to pin CGND. The diagnostic output signal during different short conditions is illustrated in <u>Figure 6</u>. Using pin DIAG as input, a voltage < 0.8 V will put the device into Fault mode.

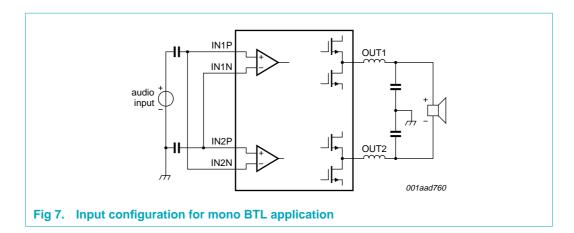


8.6 Differential inputs

For a high common-mode rejection ratio and a maximum of flexibility in the application, the audio inputs are fully differential. By connecting the inputs anti-parallel, the phase of one of the two channels can be inverted, so that the amplifier can operate as a mono BTL amplifier. The input configuration for a mono BTL application is illustrated in Figure 7.

In SE configuration it is also recommended to connect the two differential inputs in anti-phase. This has advantages for the current handling of the power supply at low signal frequencies and minimizes supply pumping (see also Section 14.8).

Class-D audio amplifier



8.7 Output voltage buffers

When pin POWERUP is set HIGH, the half supply output voltage buffers are switched on in asymmetrical supply configuration. The start-up will be pop free since the device starts switching when the capacitor on pin HVPREF and the SE capacitors are completely charged.

Output voltage buffers:

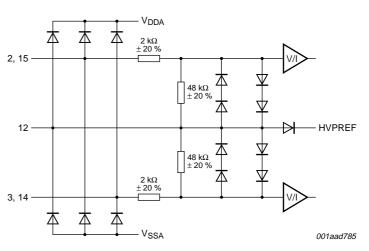
- Pins HVP1 and HVP2: The time required for charging the SE capacitor is depending on its value. The half supply voltage output is disabled when the TDA8932 is used in a symmetrical supply application.
- Pin HVPREF: This output voltage reference buffer charges the capacitor on pin HVPREF.
- Pin INREF: This output voltage reference buffer charges the input reference capacitor on pin INREF. Pin INREF applies the bias voltage for the inputs.

9. Internal circuitry

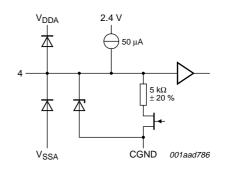
Table 7. Internal circuitry

| | | ··· , |
|-----|----------------------|--|
| Pin | Symbol | Equivalent circuit |
| 1 | $V_{SSD(HW)}$ | |
| 16 | $V_{SSD(HW)}$ | 1, 16, 17, 32 VDDA |
| 17 | $V_{SSD(HW)}$ | $\uparrow \qquad \downarrow \qquad \uparrow$ |
| 32 | V _{SSD(HW)} | V _{SSA} |
| | | 001aad784 |

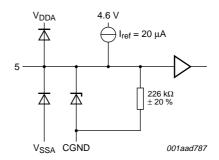




4 DIAG



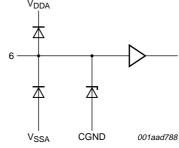
5 ENGAGE



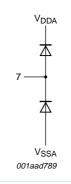
Class-D audio amplifier

Table 7. Internal circuitry ...continued

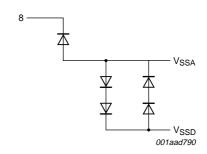
Pin Symbol Equivalent circuit 6 POWERUP



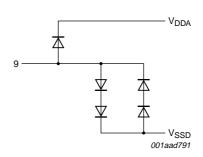
7 CGND



8 V_{DDA}



9 V_{SSA}



Class-D audio amplifier

 Table 7.
 Internal circuitry ...continued

| Pin | Symbol | Equivalent circuit | |
|-----|-------------------|--|--|
| 10 | OSCREF | V _{DDA} I _{ref} V _{SSA} 001aad792 | |
| 11 | HVPREF | VDDA 11 VSSA 001aad793 | |
| 13 | TEST | VDDA 13 VSSA 001aad795 | |
| 18 | DREF | 18 VDD VSSD VSSD 001aad796 | |
| 19 | HVP2 | | |
| 30 | HVP1 | 19, 30 VDDA VSSA 001aad797 | |
| 20 | V_{DDP2} | 20.20 | |
| 23 | V_{SSP2} | 20, 29 —— | |
| 26 | V _{SSP1} | 本 | |
| 29 | V_{DDP1} | 23, 26 001aad798 | |

Class-D audio amplifier

 Table 7.
 Internal circuitry ...continued

| Table 7. | internal circui | |
|----------|-----------------|---|
| Pin | Symbol | Equivalent circuit |
| 21 | BOOT2 | |
| 28 | BOOT1 | 21, 28 OUT1, OUT2 001aad799 |
| 22 | OUT2 | |
| 27 | OUT1 | VDDP1, VDDP2 VSSP1, VSSP2 001aad800 |
| 24 | STAB2 | |
| 25 | STAB1 | V _{DDA} 24, 25 V _{SSP1} , V _{SSP2} 001aad801 |
| 31 | OSCIO | DREF VSSD 001aad802 |

Class-D audio amplifier

10. Limiting values

Table 8. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| | | - · · | | <u> </u> | | |
|------------------|--------------------------------|---------------------------------|-----|----------------------------|----------------|------|
| Symbol | Parameter | Conditions | | Min | Max | Unit |
| V_{P} | supply voltage | asymmetrical supply | [1] | -0.3 | +40 | V |
| V_x | voltage on pin x | | | | | |
| | IN1P, IN1N, INP2, IN2N | | [2] | -5 | +5 | V |
| | OSCREF, OSCIO, TEST | | [3] | $V_{\text{SSD(HW)}} - 0.3$ | 5 | V |
| | POWERUP, ENGAGE, DIAG | | [4] | V _{CGND} – 0.3 | 6 | V |
| | all other pins | | [5] | $V_{SS}-0.3$ | $V_{DD} + 0.3$ | V |
| I _{ORM} | repetitive peak output current | maximum output current limiting | [6] | 4 | - | Α |
| Tj | junction temperature | | | - | 150 | °C |
| T _{stg} | storage temperature | | | -55 | +150 | °C |
| T_{amb} | ambient temperature | | | -40 | +85 | °C |
| Р | power dissipation | | | - | 5 | W |
| | | | | | | |

^[1] $V_P = V_{DDP1} - V_{SSP1} = V_{DDP2} - V_{SSP2}$.

11. Thermal characteristics

Table 9. Thermal characteristics

| age nermal resistance from unction to ambient | free air natural convection JEDEC test board | [1] | | | | |
|---|--|--|---|--|--|--|
| | | [1] | | | | |
| inction to ambient | JEDEC test board | [1] | | | | |
| | | | - | 41 | 44 | K/W |
| | 2 layer application board | | - | 44 | - | K/W |
| nermal resistance from inction to lead | | | - | - | 30 | K/W |
| nermal resistance from inction to top of package | | [2] | - | - | 8 | K/W |
| ? package | | | | | | |
| thermal resistance from | free air natural convection | | | | | |
| inction to ambient | JEDEC test board | <u>[1]</u> | - | 47 | 50 | K/W |
| | 2 layer application board | | - | 48 | - | K/W |
| nermal resistance from Inction to case | free air natural convection | | - | 4.7 | - | K/W |
| וו ווג ווג | ermal resistance from nction to top of package package ermal resistance from nction to ambient ermal resistance from | ermal resistance from nction to top of package package ermal resistance from nction to ambient JEDEC test board 2 layer application board 2 layer application 2 layer application 2 layer application 3 layer 4 l | remail resistance from notion to top of package package ermal resistance from notion to ambient free air natural convection JEDEC test board 2 layer application board ermal resistance from free air natural convection | remail resistance from notion to top of package package ermal resistance from notion to ambient The content of the conten | remail resistance from notion to top of package package ermal resistance from notion to ambient The content of the conten | ermal resistance from notion to top of package package ermal resistance from notion to ambient Image: Package Image: P |

^[1] Measured in a JEDEC high K-factor test board (standard EIA/JESD 51-7) in free air with natural convection.

TDA8932_1

^[2] Measured with respect to pin INREF; $V_x < V_{DD} + 0.3 V$.

^[3] Measured with respect to pin $V_{SSD(HW)}$; $V_x < V_{DD} + 0.3 \text{ V}$.

^[4] Measured with respect to pin CGND; $V_x < V_{DD} + 0.3 \text{ V}$.

^[5] $V_{SS} = V_{SSP1} = V_{SSP2}$; $V_{DD} = V_{DDP1} = V_{DDP2}$.

^[6] Current limiting concept.

^[2] Strongly depends on where you measure on the package.

Class-D audio amplifier

12. Static characteristics

Table 10. Static characteristics

 V_P = 22 V; f_{osc} = 320 kHz; T_{amb} = 25 °C; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-------------------------------|--|----------------------------|-------------------|----------------------------|-----------|
| Supply | | | | | | |
| V_P | supply voltage | asymmetrical supply | 10 | 22 | 36 | V |
| | | symmetrical supply | ±5 | ±11 | ±18 | V |
| l _P | supply current | Sleep mode; no load | - | 0.6 | 1 | mΑ |
| $I_{q(tot)}$ | total quiescent current | Operating mode; no load, snubbers and filter connected | - | 40 | 80 | mA |
| Series res | istance output power switch | nes | | | | |
| R _{DSon} | drain-source on-state | T _j = 25 °C | - | 150 | - | $m\Omega$ |
| | resistance | T _j = 125 °C | - | 234 | - | $m\Omega$ |
| Power-up | input: pin POWERUP[1] | | | | | |
| VI | input voltage | | 0 | - | 6.0 | V |
| I _I | input current | V _I = 3 V | - | 1 | 20 | μΑ |
| V_{IL} | LOW-level input voltage | | 0 | - | 0.8 | V |
| V _{IH} | HIGH-level input voltage | | 2 | - | 6.0 | V |
| Engage in | put: pin ENGAGE[1] | | | | | |
| Vo | output voltage | | 4.2 | 4.6 | 5.0 | V |
| VI | input voltage | | 0 | - | 6.0 | V |
| Io | output current | V _I = 3 V | - | 20 | 40 | μΑ |
| V _{IL} | LOW-level input voltage | | 0 | - | 8.0 | V |
| V_{IH} | HIGH-level input voltage | | 3 | - | 6.0 | V |
| Diagnosti | c output: pin DIAG[1] | | | | | |
| Vo | output voltage | protection activated; see Table 5 | - | - | 0.8 | V |
| | | Operating mode | 2 | 2.5 | 3.3 | V |
| Bias volta | ge for inputs: pin INREF | | | | | |
| V _{O(bias)} | bias output voltage | with respect to pin V _{SSA} | - | 2.1 | - | V |
| Half suppl | y voltage | | | | | |
| Pins HVP1 | and HVP2 | | | | | |
| V _O | output voltage | half supply voltage to charge SE capacitor | 0.5V _P – 0.2 | 0.5V _P | 0.5V _P + 0.2 | V |
| lo | output current | $V_{HVP1} = V_O - 1 V;$ $V_{HVP2} = V_O - 1 V$ | - | 50 | - | mA |
| Pin HVPRI | F | | | | | |
| V _O | output voltage | half supply reference voltage in Mute mode | 0.5V _P – 0.2 | 0.5V _P | 0.5V _P + 0.2 | V |
| Reference | voltage for internal logic: p | in DREF | | | | |
| Vo | output voltage | | 4.5 | 4.8 | 5.1 | V |

Class-D audio amplifier

 Table 10.
 Static characteristics ...continued

 V_P = 22 V; f_{osc} = 320 kHz; T_{amb} = 25 °C; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------------|--|--|-----|------|-----|------|
| Amplifier o | outputs: pins OUT1 and OUT2 | | | | | |
| V _{O(offset)} | output offset voltage | SE; with respect to pin HVPREF | | | | |
| | | Mute mode | - | - | 15 | mV |
| | | Operating mode | - | - | 100 | mV |
| | | BTL | | | | |
| | | Mute mode | - | - | 20 | mV |
| | | Operating mode | - | - | 150 | mV |
| Stabilizer o | output: pins STAB1 and STAB | 2 | | | | |
| V _O | output voltage | Mute mode and Operating mode; with respect to pins V_{SSP1} and V_{SSP2} | 10 | 11 | 12 | V |
| Voltage pro | otections | | | | | |
| $V_{P(uvp)}$ | undervoltage protection supply voltage | | 8.0 | 9.5 | 10 | V |
| $V_{P(ovp)}$ | overvoltage protection supply voltage | | 36 | 38.5 | 40 | V |
| $V_{P(th)(ubp)I}$ | low unbalance protection threshold supply voltage | | | - | 18 | V |
| $V_{P(th)(ubp)h}$ | high unbalance protection threshold supply voltage | V _{HVPREF} = 11 V | 29 | - | - | V |
| Current pro | otections | | | | | |
| I _{O(ocp)} | overcurrent protection output current | current limiting | 4 | 5 | - | Α |
| Temperatu | re protections | | | | | |
| T _{act(th_prot)} | thermal protection activation temperature | | 155 | - | 160 | °C |
| $T_{act(th_fold)}$ | thermal foldback activation temperature | | 140 | - | 150 | °C |
| Oscillator r | reference; pin OSCIO[2] | | | | | |
| V _{IH} | HIGH-level input voltage | | 4.0 | - | 5 | V |
| V _{IL} | LOW-level input voltage | | 0 | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | | 4.0 | - | 5 | V |
| V _{OL} | LOW-level output voltage | | 0 | - | 0.8 | V |
| N _{slave(max)} | maximum number of slaves | driven by one master | 12 | - | - | - |

^[1] Measured with respect to pin CGND.

^[2] Measured with respect to pin $V_{SSD(HW)}$.

Class-D audio amplifier

13. Dynamic characteristics

Table 11. Switching characteristics

 $V_P = 22 \text{ V}; T_{amb} = 25 \,^{\circ}\text{C}; \text{ unless otherwise specified.}$

| | | • | | | | |
|---------------------|--------------------------|------------------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Internal o | oscillator | | | | | |
| f _{osc} | oscillator frequency | $R_{\rm osc} = 39 \text{ k}\Omega$ | - | 320 | - | kHz |
| | | range | 300 | - | 500 | kHz |
| Timing P | WM output: pins OUT1 and | OUT2 | | | | |
| t _r | rise time | $I_O = 0 A$ | - | 10 | - | ns |
| t _f | fall time | $I_O = 0 A$ | - | 10 | - | ns |
| t _{w(min)} | minimum pulse width | $I_O = 0 A$ | - | 80 | - | ns |
| | | | | | | |

Table 12. SE characteristics

 V_P = 22 V; R_L = 2×4 Ω ; f_i = 1 kHz; f_{osc} = 320 kHz; R_s < 0.1 Ω [1]; T_{amb} = 25 °C; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|---------------------------------|--|--------------|----------------------|-----------------|---------------|
| P _{o(RMS)} | RMS output power | continuous time output power per channel | [2] | | | |
| | | $R_L = 4 \Omega$; $V_P = 22 V$ | | | | |
| | | THD+N = 0.5 %, $f_i = 1 \text{ kHz}$ | 11 | 12 | - | W |
| | | THD+N = 0.5 %, f_i = 100 Hz | - | 12 | - | W |
| | | THD+N = 10 %, $f_i = 1 \text{ kHz}$ | 14 | 15 | - | W |
| | | THD+N = 10 %, f_i = 100 Hz | - | 15 | - | W |
| | | $R_L = 8 \Omega$; $V_P = 30 V$ | | | | |
| | | THD+N = 0.5 %, $f_i = 1 \text{ kHz}$ | 11 | 12 | - | W |
| | | THD+N = 0.5 %, f_i = 100 Hz | - | 12 | - | W |
| | | THD+N = 10 %, $f_i = 1 \text{ kHz}$ | 14 | 15 | - | W |
| | | THD+N = 10 %, f_i = 100 Hz | - | 15 | - | W |
| | | short time output power per channel | [2] | | | |
| | | $R_L = 4 \Omega$; $V_P = 29 V$ | | | | |
| | | THD+N = 0.5 % | 19 | 20 | - | W |
| | | THD+N = 10 % | 23 | 25 | - | W |
| THD+N | total harmonic distortion-plus- | P _o = 1 W | <u>[3]</u> | | | |
| | noise | $f_i = 1 \text{ kHz}$ | - | 0.015 | 0.05 | % |
| | | $f_i = 6 \text{ kHz}$ | - | 0.08 | 0.10 | % |
| G _{v(cl)} | closed loop voltage gain | $V_i = 100 \text{ mV}$; no load | 29 | 30 | 31 | dB |
| $ \Delta G_v $ | voltage gain difference | | - | 0.5 | 1 | dB |
| $\alpha_{\sf cs}$ | channel separation | $P_o = 1 W$; $f_i = 1 kHz$ | 70 | 80 | - | dB |
| SVRR | supply voltage ripple rejection | Operating mode | <u>[4]</u> | | | |
| | | f _i = 100 Hz | - | 60 | - | dB |
| | | $f_i = 1 \text{ kHz}$ | 40 | 50 | - | dB |
| $ Z_i $ | input impedance | differential | 70 | 100 | - | kΩ |
| $V_{n(o)}$ | noise output voltage | Operating mode; $R_s = 0 \Omega$ | <u>[5]</u> _ | 100 | 150 | μV |
| | | Mute mode | <u>[5]</u> _ | 70 | 100 | μV |
| -DΔ8932 1 | | | 016 | ike Philins Flectron | · . N.V. 0000 . | H - 2 - 1 - 4 |

Class-D audio amplifier

Table 12. SE characteristics ... continued

 V_P = 22 V; R_L = 2×4 Ω ; f_i = 1 kHz; f_{osc} = 320 kHz; R_s < 0.1 Ω [1]; T_{amb} = 25 °C; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|-----------------------------|--|-----|-----|-----|------|
| $V_{O(mute)}$ | mute output voltage | Mute mode; $V_i = 1 \text{ V (RMS)}$ and $f_i = 1 \text{ kHz}$ | - | 100 | - | μV |
| CMRR | common mode rejection ratio | $V_{i(cm)} = 1 V (RMS)$ | 56 | 75 | - | dB |
| η_{po} | output power efficiency | $P_0 = 15 \text{ W}$ | | | | |
| | | $V_P = 22 \text{ V}; \text{ R}_L = 4 \Omega$ | 90 | 92 | - | % |
| | | $V_P = 30 \text{ V}; \text{ R}_L = 8 \Omega$ | 91 | 93 | - | % |

- [1] R_s is the series resistance of inductor of low-pass LC filter in the application.
- [2] Output power is measured indirectly; based on R_{DSon} measurement.
- [3] THD+N is measured in a bandwidth of 20 Hz to 20 kHz, AES17 brick wall.
- [4] Maximum $V_{ripple} = 2 V (p-p)$; $R_s = 0 \Omega$.
- [5] B = 20 Hz to 20 kHz, AES17 brick wall.

Table 13. BTL characteristics

 $V_P = 22~V;~R_L = 8~\Omega;~f_i = 1~kHz;~f_{osc} = 320~kHz;~R_s < 0.1~\Omega^{\boxed{11}};~T_{amb} = 25~^{\circ}C;~unless~otherwise~specified.$

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|---------------------------------|---------------------------------------|--------------|--------------------|------------------|----------------|
| P _{o(RMS)} | RMS output power | continuous time output power | [2] | | | |
| | | $R_L = 4 \Omega; V_P = 12 V$ | | | | |
| | | THD+N = 0.5 %; $f_i = 1 \text{ kHz}$ | 11 | 12 | - | W |
| | | THD+N = 0.5 %; f_i = 100 Hz | - | 12 | - | W |
| | | THD+N = 10 %; $f_i = 1 \text{ kHz}$ | 14 | 15 | - | W |
| | | THD+N = 10 %; f _i = 100 Hz | - | 15 | - | W |
| | | $R_L = 8 \Omega; V_P = 22 V$ | | | | |
| | | THD+N = 0.5 %; $f_i = 1 \text{ kHz}$ | 23 | 24 | - | W |
| | | THD+N = 0.5 %; f_i = 100 Hz | - | 24 | - | W |
| | | THD+N = 10 %; $f_i = 1 \text{ kHz}$ | 28 | 30 | - | W |
| | | THD+N = 10 %; f _i = 100 Hz | - | 30 | - | W |
| | | short time output power | [2] | | | |
| | | $R_L = 4 \Omega; V_P = 15 V$ | | | | |
| | | THD+N = 0.5 % | 19 | 20 | - | W |
| | | THD+N = 10 % | 23 | 25 | - | W |
| | | $R_L = 8 \Omega; V_P = 29 V$ | | | | |
| | | THD+N = 0.5 % | 38 | 40 | - | W |
| | | THD+N = 10 % | 47 | 50 | - | W |
| THD+N | total harmonic distortion-plus- | $P_0 = 1 W$ | <u>[3]</u> | | | |
| | noise | f _i = 1 kHz | - | 0.04 | 0.1 | % |
| | | f _i = 6 kHz | - | 0.04 | 0.1 | % |
| G _{v(cl)} | closed loop voltage gain | | 35 | 36 | 37 | dB |
| SVRR | supply voltage ripple rejection | Operating mode | <u>[4]</u> | | | |
| | | f _i = 100 Hz | - | 75 | - | dB |
| | | f _i = 1000 Hz | 70 | 75 | - | dB |
| | | sleep; f _i = 100 Hz | <u>[4]</u> _ | 80 | - | dB |
| TDA8932_1 | | | © Koninkli | jke Philips Electr | onics N.V. 2006. | All rights res |
| | | | | | | |

Class-D audio amplifier

Table 13. BTL characteristics ...continued

 $V_P = 22~V;~R_L = 8~\Omega;~f_i = 1~kHz;~f_{osc} = 320~kHz;~R_s < 0.1~\Omega^{\boxed{11}};~T_{amb} = 25~^{\circ}C;~unless~otherwise~specified.$

| | 2 , , , , , , | · ame | | | | |
|---------------|-----------------------------|--|-------|-----|-----|-----------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| $ Z_i $ | input impedance | differential | 35 | 50 | | $k\Omega$ |
| $V_{n(o)}$ | noise output voltage | $R_s = 0 \Omega$ | | | | |
| | | Operating mode | [5] _ | 100 | 150 | μV |
| | | Mute mode | [5] _ | 70 | 100 | μV |
| $V_{O(mute)}$ | mute output voltage | Mute mode; $V_i = 1 \text{ V (RMS)}$ and $f_i = 1 \text{ kHz}$ | - | 100 | - | μV |
| CMRR | common mode rejection ratio | $V_{i(cm)} = 1 V (RMS)$ | 56 | 75 | - | dB |
| ηρο | output power efficiency | P_{o} = 15 W; V_{P} = 12 V and R_{L} = 4 Ω | 88 | 90 | - | % |
| | | P_0 = 30 W; V_P = 22 V and R_L = 8 Ω | 90 | 92 | - | % |
| | | | | | | |

^[1] R_s is the series resistance of inductor and capacitor of low-pass LC filter in the application.

^[2] Output power is measured indirectly; based on R_{DSon} measurement.

^[3] THD+N is measured in a bandwidth of 20 Hz to 20 kHz, AES17 brick wall.

^[4] Maximum $V_{ripple} = 2 V (p-p)$; $R_s = 0 \Omega$.

^[5] B = 20 Hz to 20 kHz, AES17 brick wall.

Class-D audio amplifier

14. Application information

14.1 Output power estimation

The output power P_o at THD+N = 0.5 %, just before clipping, for the SE and BTL configuration can be estimated using Equation 2 and Equation 3.

SE configuration:

$$P_{o(0.5\%)} = \frac{\left[\left(\frac{R_L}{R_L + R_{DSon} + R_s + R_{ESR}}\right) \times (I - t_{w(min)} \times f_{osc}) \times V_P\right]^2}{8 \times R_I}$$
 (2)

BTL configuration:

$$P_{o(0.5\%)} = \frac{\left[\left(\frac{R_L}{R_L + 2 \times (R_{DSon} + R_s)} \right) \times (1 - t_{w(min)} \times f_{osc}) \times V_P \right]^2}{2 \times R_I}$$
(3)

Where:

 V_P = supply voltage $V_{DDP1} - V_{SSP1}$ [V] or $V_{DDP2} - V_{SSP2}$ [V]

 R_L = load impedance $[\Omega]$

 R_{DSon} = on-resistance power switch [Ω]

 R_s = series resistance output inductor $[\Omega]$

 R_{ESR} = equivalent series resistance SE capacitor [Ω]

 $t_{w(min)}$ = minimum pulse width [s]; 80 ns typical

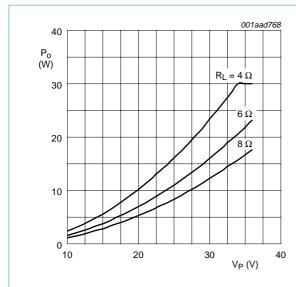
 f_{osc} = oscillator frequency [Hz]; 320 kHz typical with R_{osc} = 39 k Ω

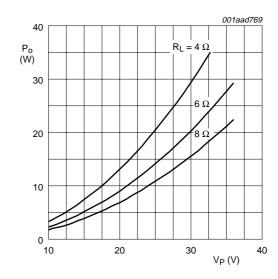
The output power P_0 at THD+N = 10 % can be estimated by:

$$P_{o(10\%)} = 1.25 \times P_{o(0.5\%)} \tag{4}$$

Figure 8 and Figure 9 show the estimated output power at THD+N = 0.5 % and THD+N = 10 % as a function of the supply voltage for SE and BTL configurations at different load impedances. The output power is calculated with: R_{DSon} = 0.15 Ω (at T_i = 25 °C), R_s = 0.05 Ω, R_{ESR} = 0.05 Ω and $I_{O(ocp)}$ = 4 A (minimum).

001aad771



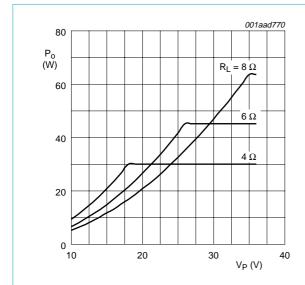


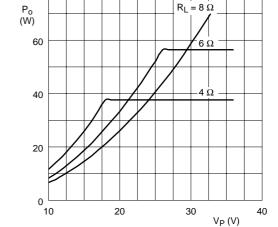
a. THD+N = 0.5 %

Fig 8. SE output power as a function of supply voltage



80





a. THD+N = 0.5 %

Fig 9. BTL output power as a function of supply voltage

b. THD+N = 10 %

Class-D audio amplifier

14.2 Output current limiting

The peak output current $I_{O(max)}$ is internally limited above a level of 4 A (minimum). During normal operation the output current should not exceed this threshold level of 4 A otherwise the output signal is distorted. The peak output current in SE or BTL configurations can be estimated using Equation 5 and Equation 6.

SE configuration:

$$I_{O(max)} \le \frac{0.5 \times V_P}{R_L + R_{DSon} + R_s + R_{ESR}} \le 4 A$$
 (5)

BTL configuration:

$$I_{O(max)} \le \frac{V_P}{R_I + 2 \times (R_{DSon} + R_s)} \le 4 A$$
 (6)

Where:

 V_P = supply voltage $V_{DDP1} - V_{SSP1}$ [V] or $V_{DDP2} - V_{SSP2}$ [V]

 R_L = load impedance $[\Omega]$

 R_{DSon} = on-resistance power switch [Ω]

 R_s = series resistance output inductor $[\Omega]$

 R_{ESR} = equivalent series resistance SE capacitor [Ω]

Example:

A 4 Ω speaker in the BTL configuration can be used until a supply voltage of 18 V without running into current limiting. Current limiting (clipping) will avoid audio holes but it causes a comparable distortion like voltage clipping.

14.3 Speaker configuration and impedance

For a flat frequency response (second-order Butterworth filter) it is necessary to change the low-pass filter components L_{LC} and C_{LC} according to the speaker configuration and impedance. Table 14 shows the practical required values.

Table 14. Filter component values

| Configuration | R _L (Ω) | L _{LC} (μH) | C _{LC} (nF) |
|---------------|---------------------------|----------------------|----------------------|
| SE | 4 | 22 | 680 |
| | 6 | 33 | 470 |
| | 8 | 47 | 330 |
| BTL | 4 | 10 | 1500 |
| | 6 | 15 | 1000 |
| | 8 | 22 | 680 |

14.4 Single-ended capacitor

The SE capacitor is forming a high-pass filter with the speaker impedance. So the frequency response will roll-off with 20 dB per decade below f_{-3dB} (3 dB cut-off frequency).

TDA8932_1

Class-D audio amplifier

The 3 dB cut-off frequency is equal to:

$$f_{-3dB} = \frac{1}{2\pi \times R_L \times C_{SE}} \tag{7}$$

Where:

 $f_{-3dB} = 3 dB cut-off frequency [\Omega]$

 R_L = load impedance [Ω]

C_{SE} = single-ended capacitance [F]; see Figure 29

<u>Table 15</u> is showing an overview of the required SE capacitor values in case of 60 Hz, 40 Hz or 20 Hz 3 dB cut-off frequency.

Table 15. SE capacitor values

| Impedance (Ω) | C _{SE} (μF) | | |
|------------------------|---------------------------|---------------------------|---------------------------|
| | f _{-3dB} = 60 Hz | f _{-3dB} = 40 Hz | f _{-3dB} = 20 Hz |
| 4 | 680 | 1000 | 2200 |
| 6 | 470 | 680 | 1500 |
| 8 | 330 | 470 | 1000 |

14.5 Gain reduction

The gain of the TDA8932 is internally fixed at 30 dB for SE (or 36 dB for BTL). The gain can be reduced by a resistive voltage divider at the input (see Figure 10).

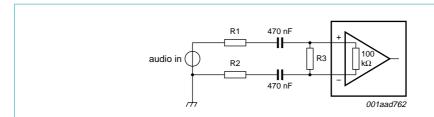


Fig 10. Input configuration for reducing gain

When applying a resistive divider, the total closed loop gain $G_{v(tot)}$ can be calculated by Equation 8 and Equation 9:

$$G_{v(tot)} = G_{v(cl)} + 20\log \times \left[\frac{R_{EQ}}{R_{EQ} + (RI + R2)}\right]$$
 (8)

Where:

 $G_{v(tot)}$ = total closed loop voltage gain [dB]

 $G_{v(cl)}$ = closed loop voltage gain, fixed at 30 dB for SE [dB]

 R_{EQ} = equivalent resistance, R3 and Z_i [Ω]

R1 = series resistors $[\Omega]$

R2 = series resistors $[\Omega]$

Class-D audio amplifier

$$R_{EQ} = \frac{R3 \times Z_i}{R3 + Z_i} \tag{9}$$

Where:

 R_{FO} = equivalent resistance $[\Omega]$

R3 = parallel resistor $[\Omega]$

Z_i = internal input impedance

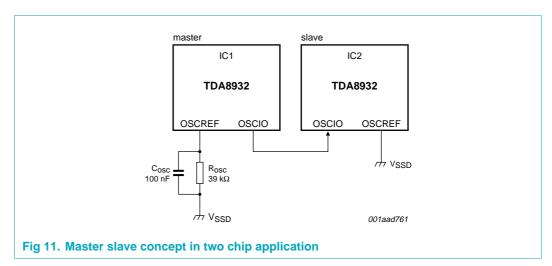
Example:

Substituting R1 = R2 = 4.7 k Ω , Z_i = 100 k Ω and R3 = 22 k Ω in Equation 8 and Equation 9 results in a gain of $G_{v(tot)}$ = 26.3 dB.

14.6 Device synchronization

If two or more TDA8932 devices are used in one application it is recommended that all devices are synchronized running at the same switching frequency to avoid beat tones. Synchronization can be realized by connecting all OSCIO pins together and configure one of the TDA8932 devices as master, while the other TDA8932 devices are configured as slave (see Figure 11).

A device is configured as master when connecting a resistor between pins OSCREF and $V_{SSD(HW)}$ setting the carrier frequency. Pin OSCIO of the master is then configured as an oscillator output for synchronization. The OSCREF pins of the slave devices should be shorted to $V_{SSD(HW)}$ configuring pin OSCIO as an input.



14.7 Thermal behavior (printed-circuit board considerations)

The heatsink in the application with the TDA8932 is made with the copper on the Printed-Circuit Board (PCB). The TDA8932 uses the four corner leads (pins 1, 16, 17 and 32) for heat transfer from the die to the PCB. The thermal foldback will limit the maximum junction temperature to $140\,^{\circ}$ C.

Class-D audio amplifier

Equation 10 shows the relation between the maximum allowable power dissipation P and the thermal resistance from junction to ambient.

$$R_{th(j-a)} = \frac{T_{j(max)} - T_{amb}}{P} \tag{10}$$

Where:

R_{th(i-a)} = thermal resistance from junction to ambient

 $T_{j(max)}$ = maximum junction temperature

 T_{amb} = ambient temperature

P = power dissipation which is determined by the efficiency of the TDA8932

The power dissipation is shown in Figure 21 (SE) and Figure 28 (BTL).

The thermal resistance as a function of the PCB area (35 μm copper) is shown in Figure 12.

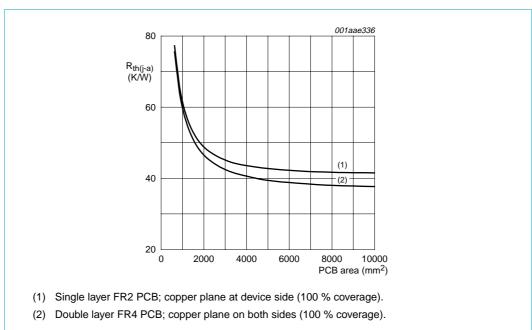


Fig 12. Thermal resistance as a function of the PCB area

Example 1

- At V_P = 30 V and P₀ = 2 × 15 W into 8 Ω (THD+N = 10 % continuous), the power dissipation P = 2.3 W at P₀ = 15 W (see Figure 21).
- $T_{j(max)} = 125 \, ^{\circ}\text{C}$ and $T_{amb} = 25 \, ^{\circ}\text{C}$.

The required thermal resistance $R_{th(j-a)} = 100 / 2.3 = 43 \text{ K/W}$.

Class-D audio amplifier

Example 2

In case of music output power at 25 % of the rated power, the $T_{i(max)}$ is much lower.

- At $V_P = 30$ V and $P_o = 2 \times (0.25 \times 15) = 2 \times 3.75$ W into 8 Ω , the power dissipation P = 1.6 W at $P_o = 3.75$ W (see Figure 21)
- R_{th(j-a)} = 43 K/W

The maximum junction temperature $T_{j(max)} = 25 + 1.6 \times 43 = 93.8$ °C.

14.8 Pumping effects

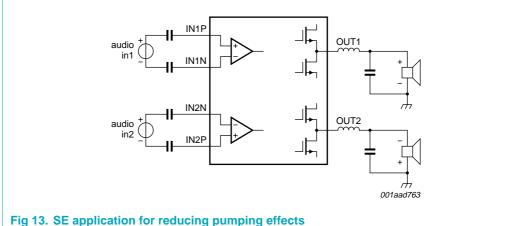
When the amplifier is used in a SE configuration, a so-called 'pumping effect' can occur. During one switching interval, energy is taken from one supply (e.g. V_{DDP1}), while a part of that energy is delivered back to the other supply line (e.g. V_{SSP1}) and visa versa. When the power supply cannot sink energy, the voltage across the output capacitors of that power supply will increase.

The voltage increase caused by the pumping effect depends on:

- Speaker impedance
- Supply voltage
- · Audio signal frequency
- Value of decoupling capacitors on supply lines
- · Source and sink currents of other channels

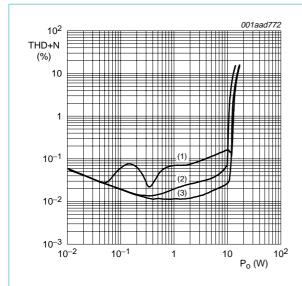
The pumping effect should not cause a malfunction of either the audio amplifier and/or the power supply. For instance, this malfunction can be caused by triggering of the undervoltage or overvoltage protection of the amplifier.

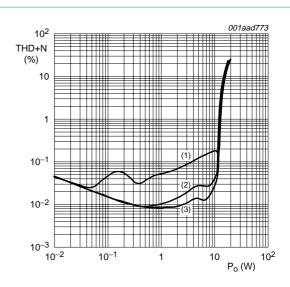
Pumping effects in a SE configuration can be minimized by connecting audio inputs in anti-phase and change the polarity of one speaker. This is illustrated in Figure 13.



rig 13. 3E application for reducing pumping effects

14.9 SE curves measured in reference design

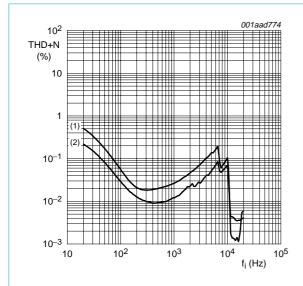


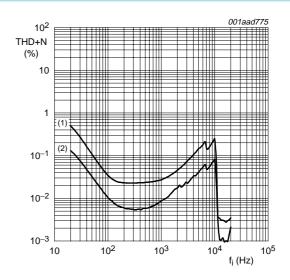


- a. $V_P = 22 \text{ V}$; $R_L = 2 \times 4 \Omega$
- (1) $f_i = 6 \text{ kHz}$
- (2) $f_i = 100 \text{ Hz}$
- (3) $f_i = 1 \text{ kHz}$

b. $V_P = 30 \text{ V}$; $R_L = 2 \times 8 \Omega$





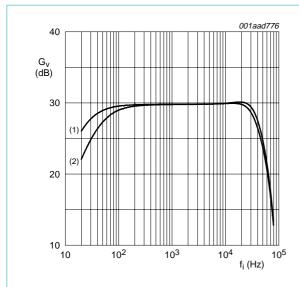


b. $V_P = 30 \text{ V}$; $R_L = 2 \times 8 \Omega$

- a. $V_P = 22 \text{ V}$; $R_L = 2 \times 4 \Omega$
- (1) $P_0 = 10 \text{ W}$
- (2) $P_0 = 1 W$

Fig 15. Total harmonic distortion-plus-noise as a function of frequency

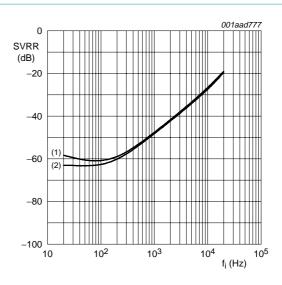
Class-D audio amplifier



 V_i = 100 mV (RMS); R_i = 0 Ω ; C_{SE} = 1000 μF

- (1) $V_P = 30 \text{ V}; R_L = 2 \times 8 \Omega$
- (2) $V_P = 22 V; R_L = 2 \times 4 \Omega$

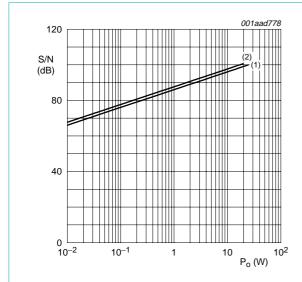
Fig 16. Gain as a function of frequency



 $V_{ripple} = 500 \text{ mV (RMS) referenced to ground;} \\ R_i = 0 \ \Omega \text{ (shorted input)}$

- (1) $V_P = 30 \text{ V}; R_L = 2 \times 8 \Omega$
- (2) $V_P = 22 V; R_L = 2 \times 4 \Omega$

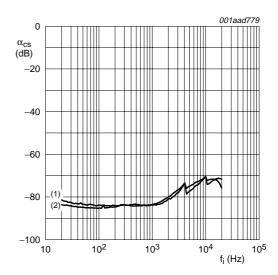
Fig 17. Supply voltage ripple rejection as a function of frequency



 V_P = 22 V; R_i = 0 Ω ; 20 kHz brick-wall filter AES17

- (1) $R_L = 2 \times 4 \Omega$
- (2) $R_L = 2 \times 8 \Omega$

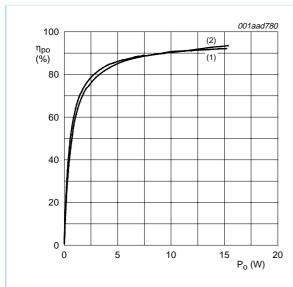
Fig 18. Signal-to-noise ratio as a function of output power



 $P_0 = 1 W; C_{HVPREF} = 47 \mu F$

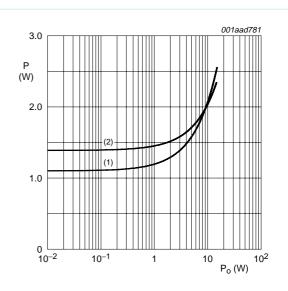
- (1) $V_P = 22 \text{ V}$; $R_L = 2 \times 4 \Omega$
- (2) $V_P = 30 \text{ V}; R_L = 2 \times 8 \Omega$

Fig 19. Channel separation as a function of frequency



- (1) $V_P = 22 \text{ V}$; $R_L = 2 \times 4 \Omega$; $f_i = 1 \text{ kHz}$
- (2) $V_P = 30 \text{ V}; R_L = 2 \times 8 \Omega; f_i = 1 \text{ kHz}$

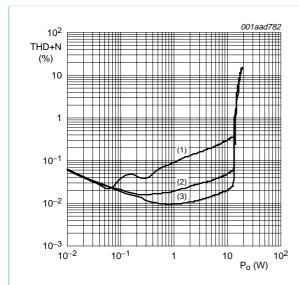
Fig 20. Output power efficiency as a function of output power



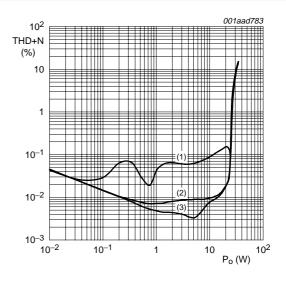
- (1) $V_P = 22 \text{ V}$; $R_L = 2 \times 4 \Omega$; $f_i = 1 \text{ kHz}$
- (2) $V_P = 30 \text{ V}$; $R_L = 2 \times 8 \Omega$; $f_i = 1 \text{ kHz}$

Fig 21. Power dissipation as a function of output power per channel (two channels driven)

14.10 BTL curves measured in reference design



- a. $V_P = 12 \text{ V}; R_L = 4 \Omega$
- (1) $f_i = 6 \text{ kHz}$
- (2) $f_i = 1 \text{ kHz}$
- (3) $f_i = 100 \text{ Hz}$

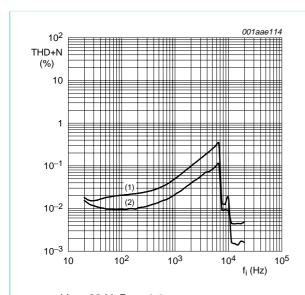


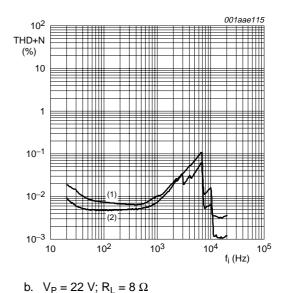
b. $V_P = 24 \text{ V}$; $R_L = 8 \Omega$

Fig 22. Total harmonic distortion-plus-noise as a function of output power

TDA8932 Philips Semiconductors

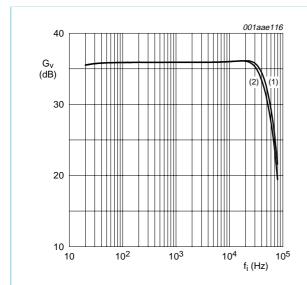
Class-D audio amplifier

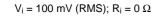




- a. $V_P = 22 \text{ V}$; $R_L = 4 \Omega$
- (1) $P_0 = 10 \text{ W}$
- (2) $P_0 = 1 W$

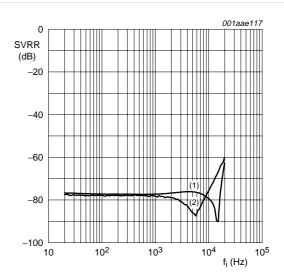
Fig 23. Total harmonic distortion-plus-noise as a function of frequency





- (1) $V_P = 12 \text{ V}; R_L = 4 \Omega$
- (2) $V_P = 24 \text{ V}; R_L = 8 \Omega$

Fig 24. Gain as a function of frequency

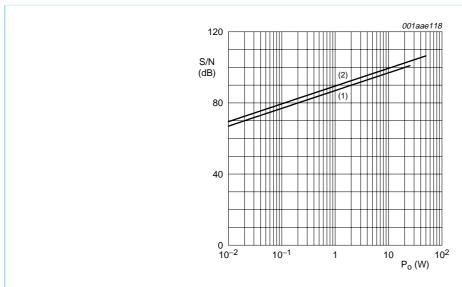


 $V_{ripple} = 500 \text{ mV (RMS)}$ referenced to ground; $R_i = 0 \Omega$ (shorted input)

- (1) $R_L = 4 \Omega$
- (2) $R_L = 8 \Omega$

Fig 25. Supply voltage ripple rejection as a function of frequency

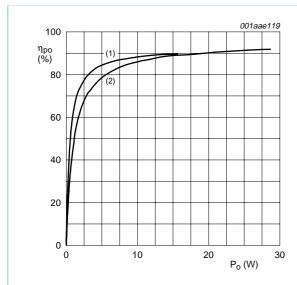
Class-D audio amplifier



 $R_i = 0 \Omega$; 20 kHz brick-wall filter AES17

- (1) $R_L = 4 \Omega$; $V_P = 15 V$
- (2) $R_L = 8 \Omega$; $V_P = 29 V$

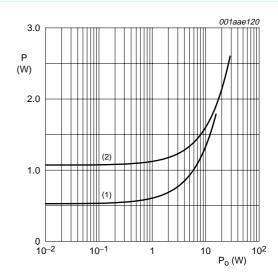
Fig 26. Signal-to-noise ratio as a function of output power





(2)
$$V_P = 22 \text{ V}; R_L = 2 \times 8 \Omega; f_i = 1 \text{ kHz}$$

Fig 27. Output power efficiency as a function of output power

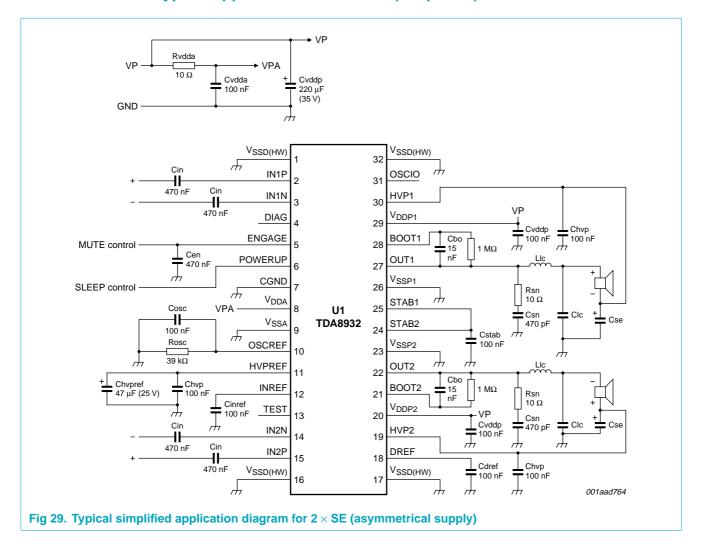


- (1) $V_P = 12 \text{ V}; R_L = 2 \times 4 \Omega; f_i = 1 \text{ kHz}$
- (2) $V_P = 22 \text{ V}; R_L = 2 \times 8 \Omega; f_i = 1 \text{ kHz}$

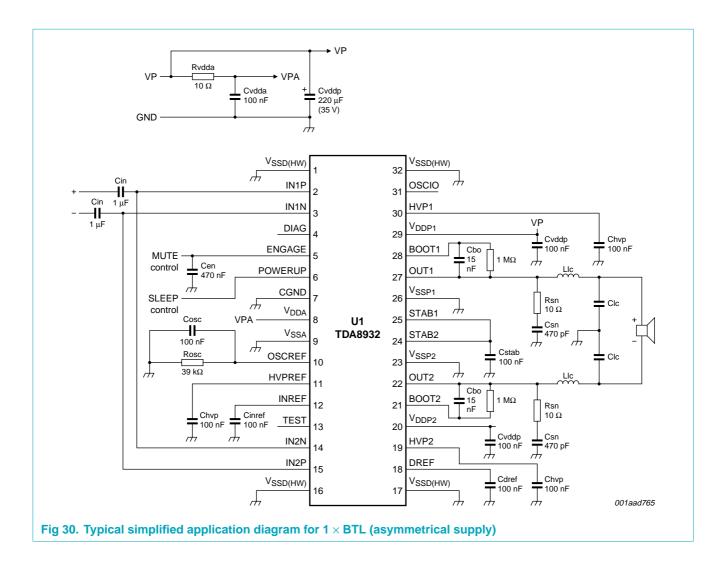
Fig 28. Power dissipation as a function of output power

Class-D audio amplifier

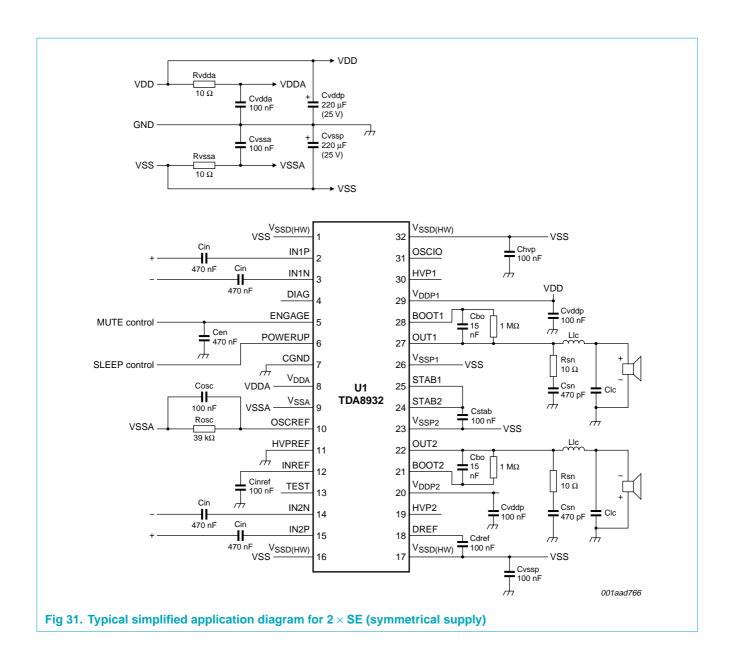
14.11 Typical application schematics (simplified)



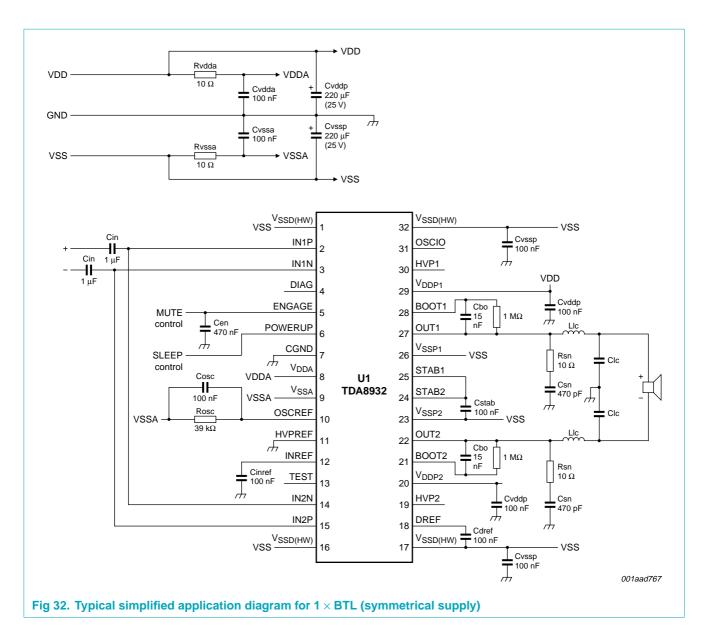
Class-D audio amplifier



Class-D audio amplifier



Class-D audio amplifier



15. Test information

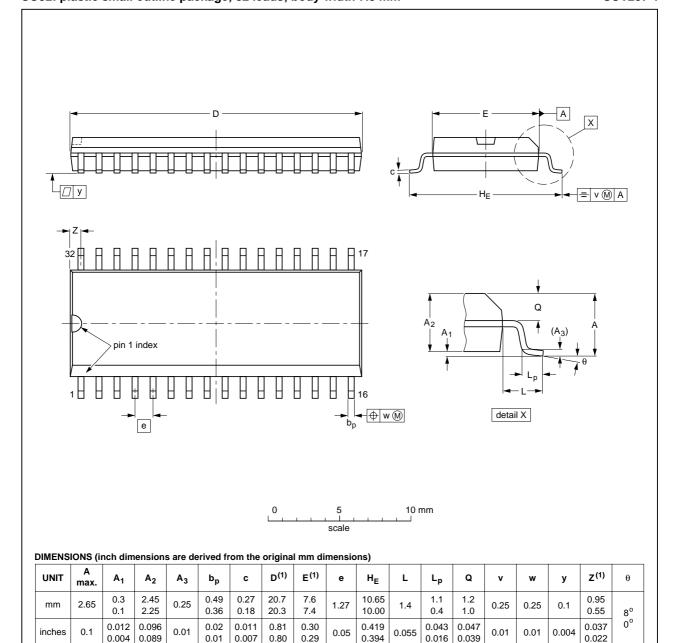
15.1 Quality information

The General Quality Specification for Integrated Circuits, SNW-FQ-611 is applicable.

16. Package outline

SO32: plastic small outline package; 32 leads; body width 7.5 mm

SOT287-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

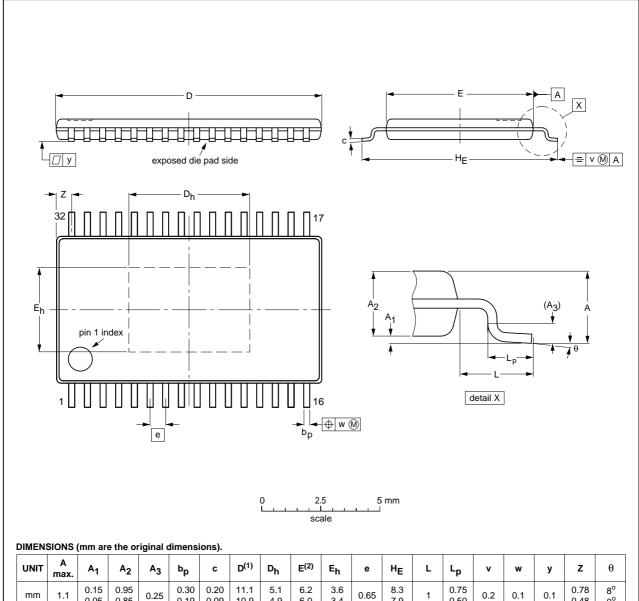
| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|----------|-----|--------|-------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT287-1 | | MO-119 | | | 00-08-17 03-02-19 |

Fig 33. Package outline SOT287-1 (SO32)

TDA8932_

HTSSOP32: plastic thermal enhanced thin shrink small outline package; 32 leads; body width 6.1 mm; lead pitch 0.65 mm; exposed die pad

SOT549-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bр | С | D ⁽¹⁾ | D _h | E ⁽²⁾ | E _h | е | HE | L | Lp | v | w | у | z | θ |
|------|-----------|----------------|----------------|----------------|--------------|--------------|------------------|----------------|------------------|----------------|------|------------|---|--------------|-----|-----|-----|--------------|----------|
| mm | 1.1 | 0.15 0.05 | 0.95 0.85 | 0.25 | 0.30 0.19 | 0.20 0.09 | 11.1 10.9 | 5.1 4.9 | 6.2 6.0 | 3.6 3.4 | 0.65 | 8.3 7.9 | 1 | 0.75 0.50 | 0.2 | 0.1 | 0.1 | 0.78 0.48 | 8° 0° |

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| EUROPEAN ISSUE DATE | ENCES | REFER | | OUTLINE |
|----------------------------------|-------|--------|-----|----------|
| PROJECTION ISSUE DATE | JEITA | JEDEC | IEC | VERSION |
| -03-04-07 05-11-02 | | MO-153 | | SOT549-1 |
| | | MO-153 | | SOT549-1 |

Fig 34. Package outline SOT549-1 (HTSSOP32)

Class-D audio amplifier

17. Soldering

17.1 Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *Data Handbook IC26; Integrated Circuit Packages* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

17.2 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Driven by legislation and environmental forces the worldwide use of lead-free solder pastes is increasing.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 seconds and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 °C to 260 °C depending on solder paste material. The top-surface temperature of the packages should preferably be kept:

- below 225 °C (SnPb process) or below 245 °C (Pb-free process)
 - for all BGA, HTSSON..T and SSOP..T packages
 - for packages with a thickness ≥ 2.5 mm
 - for packages with a thickness < 2.5 mm and a volume ≥ 350 mm³ so called thick/large packages.
- below 240 °C (SnPb process) or below 260 °C (Pb-free process) for packages with a thickness < 2.5 mm and a volume < 350 mm³ so called small/thin packages.

Moisture sensitivity precautions, as indicated on packing, must be respected at all times.

17.3 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;

TDA8932_1

Class-D audio amplifier

 smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

 For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time of the leads in the wave ranges from 3 seconds to 4 seconds at 250 °C or 265 °C, depending on solder material applied, SnPb or Pb-free respectively.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

17.4 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300\,^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 seconds to 5 seconds between 270 °C and 320 °C.

17.5 Package related soldering information

Table 16. Suitability of surface mount IC packages for wave and reflow soldering methods

| Package ^[1] | Soldering method | |
|--|-----------------------------|--------------|
| | Wave | Reflow[2] |
| BGA, HTSSONT ^[3] , LBGA, LFBGA, SQFP, SSOPT ^[3] , TFBGA, VFBGA, XSON | not suitable | suitable |
| DHVQFN, HBCC, HBGA, HLQFP, HSO, HSOP, HSQFP, HSSON, HTQFP, HTSSOP, HVQFN, HVSON, SMS | not suitable ^[4] | suitable |
| PLCC[5], SO, SOJ | suitable | suitable |
| LQFP, QFP, TQFP | not recommended[5][6] | suitable |
| SSOP, TSSOP, VSO, VSSOP | not recommended[7] | suitable |
| CWQCCNL[8], PMFP[9], WQCCNL[8] | not suitable | not suitable |

For more detailed information on the BGA packages refer to the (LF)BGA Application Note (AN01026);
 order a copy from your Philips Semiconductors sales office.

- [2] All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods.
- [3] These transparent plastic packages are extremely sensitive to reflow soldering conditions and must on no account be processed through more than one soldering cycle or subjected to infrared reflow soldering with peak temperature exceeding 217 °C ± 10 °C measured in the atmosphere of the reflow oven. The package body peak temperature must be kept as low as possible.

TDA8932_1

Class-D audio amplifier

- [4] These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- [5] If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- [6] Wave soldering is suitable for LQFP, QFP and TQFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- [7] Wave soldering is suitable for SSOP, TSSOP, VSO and VSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.
- [8] Image sensor packages in principle should not be soldered. They are mounted in sockets or delivered pre-mounted on flex foil. However, the image sensor package can be mounted by the client on a flex foil by using a hot bar soldering process. The appropriate soldering profile can be provided on request.
- [9] Hot bar soldering or manual soldering is suitable for PMFP packages.

18. Abbreviations

Table 17. Abbreviations

| Acronym | Description |
|---------|---|
| BTL | Bridge Tied Load |
| DMOS | Double diffused Metal Oxide Semiconductor |
| ESD | ElectroStatic Discharge |
| PWM | Pulse Width Modulation |
| OCP | OverCurrent Protection |
| OTP | OverTemperature Protection |
| OVP | OverVoltage Protection |
| UBP | UnBalance Protection |
| UVP | UnderVoltage Protection |
| TF | Thermal Foldback |
| WP | Window Protection |

19. Revision history

Table 18. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------|--------------|------------------------|---------------|------------|
| TDA8932_1 | 20060511 | Preliminary data sheet | - | - |

Class-D audio amplifier

20. Legal information

20.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.semiconductors.philips.com.

20.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Philips Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Philips Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

20.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, Philips Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — Philips Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Philips Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a Philips Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Philips Semiconductors accepts no liability for inclusion and/or use of Philips Semiconductors products in such equipment or applications and therefore such inclusion and/or use is for the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — Philips Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.semiconductors.philips.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by Philips Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

20.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

21. Contact information

For additional information, please visit: http://www.semiconductors.philips.com

For sales office addresses, send an email to: sales.addresses@www.semiconductors.philips.com

Class-D audio amplifier

22. Contents

| 1 | General description | . 1 |
|-----------------|---|-----------------|
| 2 | Features | . 1 |
| 3 | Applications | . 1 |
| 4 | Quick reference data | . 2 |
| 5 | Ordering information | . 2 |
| 6 | Block diagram | |
| 7 | Pinning information | |
| 7.1 | Pinning | |
| 7.2 | Pin description | |
| 8 | Functional description | . 6 |
| 8.1 | General | |
| 8.2 | Mode selection and interfacing | . 6 |
| 8.3 | Pulse width modulation frequency | |
| 8.4 | Protections | |
| 8.4.1 | Thermal Foldback (TF) | |
| 8.4.2 | OverTemperature Protection (OTP) | |
| 8.4.3 | OverCurrent Protection (OCP) | |
| 8.4.4 | Window Protection (WP) | 10 |
| 8.4.5 | Supply voltage protections | 10 |
| 8.5 | Diagnostic input and output | 11 |
| 8.6 8.7 | Differential inputs | 11 |
| 8.7 9 | Output voltage buffers | 12 13 |
| 9 10 | Internal circuitry | |
| . • | Limiting values | 17 |
| 11 | Thermal characteristics | 17 |
| 12 | Static characteristics | 18 |
| 13 | Dynamic characteristics | 20 |
| 14 | Application information | 23 |
| 14.1 | Output power estimation | |
| 14.2 | Output current limiting | |
| 14.3 | Speaker configuration and impedance | |
| 14.4 | Single-ended capacitor | |
| 14.5 | Gain reduction | |
| 14.6 14.7 | Device synchronization | 27 |
| 14.7 | Thermal behavior (printed-circuit board considerations) | 27 |
| 14.8 | Pumping effects | |
| 14.9 | SE curves measured in reference design | |
| 14.10 | BTL curves measured in reference design | 32 |
| 14.11 | Typical application schematics (simplified) | 35 |
| 15 | Test information | 38 |
| 15.1 | Quality information | |
| | | |

Soldering 41

| 17.1 | Introduction to soldering surface mount | |
|------|---|----|
| | packages | 4 |
| 17.2 | Reflow soldering | |
| 17.3 | Wave soldering | 4′ |
| 17.4 | Manual soldering | 42 |
| 17.5 | Package related soldering information | 42 |
| 18 | Abbreviations | 43 |
| 19 | Revision history | 43 |
| 20 | Legal information | 44 |
| 20.1 | Data sheet status | 44 |
| 20.2 | Definitions | 44 |
| 20.3 | Disclaimers | 44 |
| 20.4 | Trademarks | 44 |
| 21 | Contact information | 44 |
| 22 | Contents | 45 |



17

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.